AD-773 237

OPTIMIZATION OF SOLAR CELL SHIELDING FOR GEOSTATIONARY MISSIONS

M. W. Walkden

Royal Aircraft Establishment Farnborough, England

August 1973



National Technical Information Service U. S. DEPARTMENT OF COMMERCE 5285 Port Royal Road, Springfield Va. 22151



UDC 629.19.066.5 : 629.195.521.26 : 629.199.81

ROYAL AIRCRAFT ESTABLISHMENT

Technical Report 73105

Received for printing 15 June 1973

OPTIMISATION OF SOLAR CELL SHIELDING FOR GEOSTATIONARY MISSIONS

by

M. W. Walkden

SUMMARY

Equivalent IMeV electron fluences, end of life output powers and power to weight ratios are estimated for solar cells in a five year geostationary mission beginning in 1975. The study covers cell thicknesses from 125 μ m to 300 μ m, coverslip thicknesses from 25 μ m to 300 μ m, and rear shielding typical of rigid and lightweight flexible arrays.

It is concluded that the thinnest cells and shielding give the best power to weight ratio, although the choice for a particular spacecraft will be influenced by considerations of availability, cost, fragility and array area.

Departmental Reference: Space 434

CONTENTS

				Page
1	INTRO	DUCTION		3
2	COVER	SLIP/CELL/REAR SHIELD VARIANTS		4
3	ORBIT	AL ENVIRONMENT		4
4	SOLAR	CELL DAMAGE FACTORS		5
	4.1	Definition		5
	4.2	Front incidence protons		5
	4.3	Rear incidence protons		5
	4.4	Electrons		6
5	EQUIV	ALENT IMeV ELECTRON FLUX		6
6	POWER	TO WEIGHT RATIOS		8
7	DISCU	SSION		10
	7.1	Rigid array		10
	7.2	Flexible array		10
8	CONCL	JSIONS		10
Tables	s 1 - 8			12
Refere	ences			19
Illust	tratio	ns	Figures	1-21
Detach	nable a	abstract cards		-

INTRODUCTION

I

Geostationary communication satellites of the future will require more power. For this reason, there is likely to be a change from the present spinning satellites with their body mounted solar cells, to 3 axis stabilised spacecraft with large sun orientated arrays.

3

Such arrays, particularly if efforts are made to reduce weight by using thinner cells, coverslips and substrates, are more susceptible to radiation damage than the present configuration, and the array designer needs data to enable him to choose the optimum combination for a particular mission, and to estimate the probable end-of-life output power of his selected design.

In the present report, end-of-life maximum powers and power to weight ratios are derived for three thicknesses of $20 \text{mm} \times 20 \text{mm}$ solar cell with six thicknesses of coverslip and three rear shield variants, after a five year geostationary mission beginning in 1975. The variants selected are either currently available or expected to be in the near future.

This approach was considered to be less time consuming and more relevant to present needs than a complete analytical study.

Factors which determine the damage experienced by the solar cell array are the radiation environment, the time spent in that environment, and the protection from protons and electrons afforded by the solar cell coverslip at the front, and the cell substrate, etc. at the rear.

This Report uses published data of the annual solar flare proton and trapped electron fluxes¹ which spacecraft would experience at geostationary altitude in the period 1975-77. Energy dependent damage factors for various front cover/cell/rear shield combinations, which relate protons and electrons of various energies to a monoenergetic electron flux (1 MeV) are multiplied by the proton and electron populations over the energy range and summed to give an equivalent IMeV electron fluence. This fluence is extrapolated for a five year mission starting in 1975 by taking account of the variation in solar activity during this period².

The solar cell maximum power outputs at the end of the five year mission are then derived from recent RAE experimental IMeV electron degradation data and the power to weight ratios of the various combinations calculated.

2 COVERSLIP/CELL/REAR SHIELD VARIANTS

4

The variants selected for study are listed in Table 1.

Three thicknesses of cell are usually obtainable from the cell manufacturer; 125 μ m, 200 μ m and 300 μ m, the thinner the cell, higher the cost. Discrete individually mounted coverslips are obtainable in 100, 150 and 300 μ m thicknesses. Recent reported advances³ in the deposition of integral cover glasses open the way for the use of thinner covers, and integral covers down to 25 μ m were considered.

Two types of rear shield were taken into account - the folded flexible and the fold-up rigid. The flexible type was based on the design of the RAE lightweight flexible array⁴. This is 8 μ m of cell positive contact, plus 50 μ m of Silastoseal B adhesive, covering the whole cell and used for a highly emissive thermal finish, plus 50 μ m Kapton polyimide substrate covering half the cell area, plus 25 μ m of molybdenum for the four quarters of the cell interconnection rings, all scaled in the ratio of their respective areas. This shield was estimated to have a stopping power of 17 mg cm⁻². In order to establish how critical the substrate is to the cell shielding another case with the cell contact and Silastoseal B only was included.

For the rigid fold-up panel, two cases were considered, the thinnest practicable -100 μ m of aluminium (34 mg cm⁻²) and the thickest possible - infinite rear shielding.

3 ORBITAL ENVIRONMENT

Charged particle radiations at geosynchronous altitude include trapped protons and electrons, alpha particles, solar flare protons and galactic cosmic rays.

Of these, by far the most damaging to solar arrays are solar flare protons and trapped electrons. Providing the cell is completely covered, low energy trapped protons are insignificant in their effect. Source data for the latter two radiations applicable for the years 1975-77 were taken from Ref.1, and are shown in Figs.1 and 2 respectively. The data were the source of the differential fluxes used to compute the equivalent IMeV electron flux described in section 4.

The peak of the 21st sun cycle is expected to occur about 1980-82, so that if a five year mission commencing in 1975 is considered, some allowance must be made for the increased solar activity and consequential solar flare proton fluxes which will occur in the years preceding the peak. Annual proton fluxes

in 1980-82 are expected to be an order of magnitude greater than the average for $1974-77^2$, and those in the period 1978-79 about five times greater. If these values are smoothed for the five years 1975-80, it is evident that the average annual solar flare proton flux in 1975-77 should be multiplied by a factor of 10 for the five year period. This was done, but it should be pointed out that because of the uncertainty of solar flares, the predicted proton fluences may be in error by a factor of up to two.

5

The trapped electron fluxes do not vary significantly from year to year and therefore no similar correction is necessary in this case.

4 SOLAR CELL DAMAGE FACTORS

4.1 Definition

Solar cell damage factors used to convert the proton and electron populations to equivalent IMeV electron fluxes are defined as:-The number of protons or electrons of a particular energy required to produce 25% degradation in maximum power, divided by the number of IMeV electrons to produce the same maximum power degradation.

4.2 Front incidence protons

Damage factors for normal incidence protons of energies from 2 to 155 MeV were derived experimentally⁵ in 1971. Fig.3 shows the values for 2 to 100 MeV for uncovered cells. The thinnest cover slides used in this study were 150 μ m and 300 μ m. In order to obtain damage factors for cells with thinner covers, the mass range of protons in SiO₂ (Fig.4) was used to determine Fig.5, which shows the exit *versus* incident energies for the cover thicknesses considered. These data were then applied to Fig.3. Damage factors obtained in this way for covers of 25, 50, 75 and 100 μ m are shown in Fig.6. Also shown are the experimental curves for 150 and 300 μ m, which were in good agreement with calculated values. These covers have identical damage factors for energies greater than 20 MeV, and the four thinner covers for energies in excess of 10 MeV. It was assumed that all cell thicknesses have the same front damage factors.

4.3 Rear incidence protons

No measured damage factors are known to exist for rear incidence protons; however an approximate solution is postulated below.

Referring to Fig.7, when a proton is absorbed in a solar cell, most of the damage which results is done in the region where the proton comes to rest. Thus, normal incidence protons of energy E_R produce a damage stratum at a depth R_1 , which is a function of the incident energy and the rear shielding. Fig.8 illustrates this dependence. Subtraction of R_1 from the cell thickness, t, gives a second range, R_2 , for which the energy E_F , of the equivalent front entry proton may be found from Fig.9. The damage factor K_F corresponding to energy E_F , as derived from Fig.3, may then be taken as the appropriate damage factor for rear incidence protons of energy E_R . Although the approximation breaks down for protons which come to rest near the front and rear surfaces, it is sufficient to give a general shape of the damage factor curve for the shields considered. Damage factors derived in this way for the three cell thicknesses and the three rear shields are shown in Figs.10, 11 and 12, where it may be seen that for the variants considered, the damage factors are identical for energies greater than 10 MeV.

4.4 Electrons

Electron damage factors for energies of 1, 1.8 and 4 MeV for 10 ohm cm silicon solar cells were derived experimentally in 1968⁶. As these were for uncovered cells, the effect of the front covers on the incident electron energy was calculated in similar fashion as for the protons. The mass range of electrons in SiO₂ is shown in Fig.13, and the consequent attenuation of energy for the front covers is shown in Fig.14. From these data the electron damage factors for cells fitted with the six coverslips have been calculated and are shown in Fig.15. As the damage mechanism for electron penetration is primarily a collision knock-on process, the damage is not in discrete strata as in the case of protons, but is assumed to be uniformly distributed throughout the thickness of the cell. Therefore electrons leaving the shield with a particular energy are assumed to have the same effect on the cell whether they are incident from the front or the rear. Fig.16 shows the incident *versus* exit energies for the three rear shields, and Fig.17, the consequent damage factors.

5 EQUIVALENT IMeV ELECTRON FLUX

The differential flux in narrow energy bands was obtained from Figs.1 and 2. The widths of the bands in the case of protons was selected to be finest in the region where:-

- (a) damage factors are greatest
- (b) damage factors are changing most rapidly
- (c) fluxes are highest.

The proton energy bandwidths used were:-

Range	Bandwidth
1-10 MeV	0.5 MeV
10-20 MeV	2.0 MeV
20-100 MeV	10 MeV

In the case of electrons 0.2MeV intervals were used over the whole range.

It was assumed half the differential flux in each energy band was incident normally on the front cover surface and the other half on the rear shield surface.

This simplification is discussed below. Referring to Fig.18, a proton of energy E enters a cover normally and after attenuation enters the cell with energy E_1 , where it has a range R_1 in the cell, producing a damage factor K_1 . Another proton of the same energy enters the cover at angle θ to the normal. The path through the cover is longer by $1/\cos \theta$ and the energy is attenuated to E_2 . The range R_2 in the cell is therefore less, and the proton will be absorbed nearer the cell p/n junction and hence produce a higher damage factor, K_2 . Another proton of the same energy entering the cover at angle ϕ has insufficient energy to traverse the effective thickness of the cover and thus produces no damage to the cell.

In short, for a particular energy and cover/cell combination, the proton damage factor increases initially as the angle of incidence is increased from normal but when a critical angle is reached it falls to zero. The effects of omnidirer tional incidence are therefore to some extent self cancelling.

Because of this, and bearing in mind the uncertainties of solar flare prediction and the complexities of partial shielding of the array by the spacecraft body, it was decided that an attempt to modify the damage factors to take account of an omnidirectional flux would not be justified. Although some error is inherent in the simplified approach, it is likely to be an order of magnitude less than the estimates of the solar flare proton and electron fluxes.

The damage factors for the front and rear shield variants under consideration were obtained from the appropriate curves, (Fig.6, 10, 11, 12, 16 or 17), at the mid-energy point of the band. Each was then multiplied by half the differential flux in the band and the products summed. This was done at progressively higher energies until further increments produced no significant increase in the accumulated sum.

A breakdown of the proton and electron components of the equivalent IMeV electron flux for front and rear incidence irradiations is shown in Tables 2 and 3 respectively. Table 4 shows the total equivalent IMeV electron flux from both front and rear incidence. Also given is the flux through the front cover only, which may be used in calculations for body-mounted array where the rear shield is practically infinite. The data given in these tables are applicable only for the years 1975-77.

Table 5 shows the equivalent IMeV electron flux for the five year period 1975-80. As stated in section 1, the equivalent IMeV electron flux derived from the solar flare proton environment (Tables 2 and 3) was multiplied by 10 and that from the electron environment by a factor of 5. Again the effects of all front and rear covers and infinite shields are shown.

6 POWER-TO-WEIGHT RATIO

Performance data used in the computation of power-to-weight ratio were taken from RAE measurements on a small sample of Ferranti ZMS 051024 FW, (MS 36), solar cells. This recently introduced type measures $20 \text{ mm} \times 20 \text{ mm} \times 125 \mu \text{m}$, is fabricated from 10ohm cm float zone silicon and has wrap around contacts (i.e. both negative and positive on the back). It has 24 off, $25\mu \text{m}$ wide fingers on the active surface, in place of the former 6 off, $100\mu \text{m}$ wide finger pattern (MS 23). Thus the same active area is maintained with reduced internal resistance. This, together with diffusion and antireflection coating improvements, has resulted in enhanced maximum power output. The voltage current characteristics at 25° C for both types of cell is shown in Fig.19, the maximum power *versus* IMeV electron fluence is shown in Fig.20.

The maximum steady state temperature of cells in the RAE lightweight array has been estimated⁷ as 62° C. The performance of the MS 36 at this temperature is included in Fig.20.

No comparable cell characteristics are at present available for 200μ m and 300μ m thick cells. However it is shown in section 5, that the equivalent

IMeV electron fluence for the five year mission is, in general, in excess of 10^{15} 1 MeV e cm⁻². After this fluence, both 200µm and 300µm cells will have degraded to give sensibly the same output as the 125µm cell⁷. The maximum power output curves for 200µm and 300µm cells have therefore been assumed to be identical to that for the 125µm cell.

9

The actual cells used for the performance measurements were weighed and their thickness measured to determine *pro rata* the weights of the other cell thicknesses. Weights of the coverslips were calculated assuming a density of 2.32 g cm⁻³.

The specific mass of a particular combination was calculated by adding the weights of the coverslip, cell, thermal finish and substrate for 4 cm², plus the interconnects. In the case of the flexible array, (Variant 2 of Table 1), the weight of the thermal finish, interconnects and substrate amounted to 40 mg per cell. As Variant 1 was included only as a test of the adequacy of the flexible rear shield from the radiation viewpoint, it was not included in the power-to-weight estimates. The weight of the rigid substrate was assumed to be 1.6 kg m^{-2⁷} for both the shielding cases considered (Variants 3 and 4), giving, with the interconnects, a weight of 480 mg per cell.

Tables 6, 7 and 8 list the estimated equivalent IMeV electron fluences, the resulting end-of-life powers at 62° C, (taken from Fig.20) and the specific masses for 125, 200 and 300µm cells respectively.

Fig.21, derived from these tables, shows power-to-weight ratio as a function of front cover thickness for the various coverslip/cell/rear shield combinations.

These power-to-weight ratios are, of course, for the solar panel only and take no account of the other elements of the array such as the stowage, deployment and support systems and the orientation and power transfer mechanisms. In flexible arrays, the panel weight constitutes a smaller proportion of the whole than is the case with rigid types, but the ratio of panel-to-total weight increases with size, whereas in rigid types it stays practically constant. Typical ratios in the case of a lkW paddle⁷ are 0.44 for the RAE flexible type and 0.63 for the rigid type.

7.1 Rigid array

Referring to Fig.21 it is apparent that:-

7.1.1 The soler panel power-to-weight ratio, p/w, is, in all cases considered, lower than that for the flexible array. Even when the p/w is adjusted to take account of the different structure weights for a lkW array, the rigid type is still inferior to the flexible in this respect.

7.1.2 The assumption of infinite rear shielding (Variant 4) does not markedly improve the p/w ratio, even though the assumed substrate weight is unrealistically low.

7.1.3 The p/w ratio is almost insensitive to changes in the thickness of cell or coverslip, the substrate weight masking any advantages which might be gained from optimisation of cell or cover.

7.2 Flexible array

7.2.1 The panel p/w ratio increases as the coverslip thickness decreases, and this effect becomes more pronounced as the cell thickness decreases.

7.2.2 Various trades off exist between different coverslip/cell combinations. For example at $p/w = 0.109 \text{ Wg}^{-1}$, 25µm cover on a 300µm cell

	≅ 150µm cover on a 200µm cell
and at the action of T	Ξ 235μm cover on a 125μm cell
and at $p/w = 0.148 \text{ W g}^2$	25µm cover on a 200µm cell
	\equiv 120 m cover on a 125 μ m cell .

7.2.3 For covers less than 100 μ m, a 125 μ m cell shows significant advantages. For example a 25 μ m cover on a 125 μ m cell has a p/w ratio of 0.2 W g⁻¹. The next best combination (no direct trade off being possible in this case) is either a 200 μ m cell with a 25 μ m cover, or a 125 μ m cell with a 100 μ m cover, for which the p/w ratio is 0.15 W g⁻¹. In a 1kW array this amounts to a weight penalty of about 2 kg, which could result in a further 2kg penalty, as the array mechanism would require strengthening to support the extra array weight.

8 <u>CONCLUSIONS</u>

In spite of the increased radiation received by the cell, higher p/w ratios are achieved by using the thinnest coverslip/cell/rear shield combinations.

The weight saving thus achieved is significant, and could amount to tens of kilograms for a multi-kilowatt array.

Rigid arrays bear a considerable weight penalty, even for moderate power levels. Moreover they offer no opportunity for the exploitation of thinner cells and coverslips.

For flexible arrays however, many options in coverslip and cell thickness are open, integral covers yielding the best p/w ratios. The thinnest discrete coverslips are 100µm thick, and it is doubtful whether thinner ones could be produced and mounted economically. Integral covers do not impose this difficulty as they are sputtered directly onto the cell. This also offers a wider choice of cell thickness which although increasing the p/w ratio, could reduce costs. It is possible that a 200 μ m cell with an integral 25 μ m cover could be the best choice for powers between a half and one kilowatt. For higher powers however, or for the same power where weight saving is paramount, the thinnest possible coverslip/cell combination should be used. Experience indicates that a 125µm cell with a 25-50µm cover will be quite fragile, but not impracticably so. Arrays of discrete 100µm covers on 125µm cells have already been successfully manufactured and qualified⁸. Such arrays are well supported against launch vibrations in the folded state and the only other hazard is the handling of the panels during integration, inspection, test and stowage operations. With refinements in these procedures, it should be feasible to construct and qualify folding flexible arrays of integrally covered 125µm cells.

FRONT	COVER,	CELL	AND	REAR	SHIELD	VARIANTS
						the second s



Rear shields

Valiant No.ComponentsShielding mg cm^{-2}Proportion of areaEffective shielding mg cm^{-2}18 μm Cu (+ve contact of cell)7.217.250 μm Silastoseal B (thermal finish)5.015.028 μm Cu (+ve contact of cell)7.217.228 μm Cu (+ve contact of cell)7.217.230 μm Silastoseal B (thermal finish)5.015.04125.015.050 μm Silastoseal B (thermal finish)5.015.050 μm Kapton polyimide7.10.55.0
1 8 μm Cu (+ve contact of cell) 7.2 1 7.2 50 μm Silastoseal B (thermal finish) 5.0 1 5.0 1 5.0 2 8 μm Cu (+ve contact of cell) TOTAL 7.2 1 7.2 2 8 μm Cu (+ve contact of cell) 7.2 1 7.2 50μm Silastoseal B (thermal finish) 5.0 1 5.0 50μm Silastoseal B (thermal finish) 5.0 1 5.0 50μm Kapton polyimide 7.1 0.5 0.5
50 μm Silastoseal B (thermal finish) 5.0 1 5.0 TOTAL TOTAL 12 2 8 μm Cu (+ve contact of cell) 7.2 1 7.2 50μm Silastoseal B (thermal finish) 5.0 1 5.0 50μm Kapton polyimide 7.1 0.5 5.0
TOTAL 12 2 8 μm Cu (+ve contact of cell) 7.2 1 7.2 50μm Silastoseal B (thermal finish) 5.0 1 5.0 5.0 50μm Kapton polyimide 7.1 0.5 0.5 0.5
2 8 μm Cu (+ve contact of cell) 7.2 1 7.2 50μm Silastoseal B (thermal finish) 5.0 1 5.0 5.0 50μm Kapton polyimide 7.1 0.5 5.5
50μm Silastoseal B (thermal finish)5.015.050μm Kapton polyimide7.10.55.0
50µm Kapton polyimide 7.1 0.5
(substrate) 3.55
25μm molybdenum (interconnect) 25.5 0.047 1.2
TOTAL 17
3 8 µm Cu (+ve contact of 7.2 1 7.2
100µm A1 (rigid substrate) 27.0 1 27.0
TOTAL 34
4 Infinite rear shield ∞ 1 ∞

	Table 2	
BREAKDOWN OF EQUIVALENT	MeV ELECTRON FLUX FOR	FRUNT INCIDENCE (cm ⁻² yr ⁻¹)

Damag	e source			Front cover	thickness (µm)		
		25	50	75	100	150	300
Solar flare protons	1-10 MeV 10-20 MeV 20-100 MeV	1.26×10^{14} 0.21×10^{13} 0.08×10^{13}	6.47×10^{13} 0.21 × 10 ¹³ 0.08 × 10 ¹³	5.25×10^{13} 0.21×10^{13} 0.08×10^{13}	3.83×10^{13} 0.21×10^{13} 0.08×10^{13}	1.94×10^{13} 0.22×10^{13} 0.08×10^{13}	0.68×10^{13} 0.22×10^{13} 0.08×10^{13}
l	TOTAL	1.29 × 10 ¹⁴	6.76 × 10 ¹³	5.54 × 10 ¹³	4.12 × 10 ¹³	2.24 × 10 ¹³	1.0 × 10 ¹³
rapped e	lectrons	7.54 × 10 ¹³	7.09 × 10 ¹³	6.70 × 10 ¹³	6.16 × 10 ¹³	5.65 × 10 ¹³	4.25 × 10 ¹³

BREAKDOWN OF EQUIVALENT IMEV ELECTRON FLUENCE FOR REAR INCIDENCE (cm⁻² yr⁻¹)

	1			
Cell thickness (um)	Damage source	Rea	r shielding (1	ng cm ⁻²)
		12	17	34
125	Solar flare protons Solar 1-10 MeV 10-20 MeV 20-100 MeV	$\begin{array}{c} 1.61 \times 10^{14} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13} \end{array}$	$\begin{array}{c} 6.82 \times 10^{13} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13} \end{array}$	$\begin{array}{c} 4.38 \times 10^{13} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13} \end{array}$
	TOTAL	1.64×10^{14}	7.11×10^{13}	4.67×10^{13}
200	Solar 1-10 MeV flare 10-20 MeV Protons 20-100 MeV	$1.36 \times 10^{14} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13}$	$\begin{array}{r} 6.42 \times 10^{13} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13} \end{array}$	$\begin{array}{c} 4.21 \times 10^{13} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13} \end{array}$
	TOTAL	1.39×10^{14}	6.71×10^{13}	4.50×10^{13}
300	Solar flare proton	$1.08 \times 10^{14} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13}$	$5.19 \times 10^{13} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13}$	$\begin{array}{c} 2.92 \times 10^{13} \\ 0.21 \times 10^{13} \\ 0.08 \times 10^{13} \end{array}$
	TOTAL	1.11×10^{14}	5.48×10^{13}	3.21×10^{13}
125 200 300	Trapped electrons	6.82×10^{13}	6.41×10^{13}	5.38 × 10^{13}

ANNUAL EQUIVALENT 1MeV ELECTRON FLUENCE FROM SOLAR FLARE PROTONS ONLY, FRONT AND REAR INCIDENCE, DURING PERIOD 1975-77 (cm⁻² yr⁻¹)

L L		T				
		300	$\begin{array}{c} 1.7 \times 10^{14} \\ 8.1 \times 10^{13} \\ 8.1 \times 10^{13} \\ 5.7 \times 10^{13} \end{array}$	$\begin{array}{c} 1.5 \times 10^{14} \\ 7.7 \times 10^{13} \\ 5.5 \times 10^{13} \end{array}$	$\begin{array}{c} 1.2 \times 10^{14} \\ 6.5 \times 10^{13} \\ 4.2 \times 10^{13} \end{array}$	1.0 × 10 ¹³
	~	150	$\begin{array}{c} 1.9 \times 10^{14} \\ 9.3 \times 10^{13} \\ 6.9 \times 10^{13} \end{array}$	$\begin{array}{c} 1.6 \times 10^{14} \\ 8.9 \times 10^{13} \\ 7.7 \times 10^{13} \end{array}$	$\begin{array}{cccc} 1.3 \times 10^{14} \\ 7.7 \times 10^{13} \\ 5.4 \times 10^{13} \end{array}$	2.2 × 10 ¹³
	thickness (µm	100	2.1×10^{14} 1.1×10^{14} 8.9×10^{13}	$\begin{array}{rrrr} 1.8 \times 10^{14} \\ 1.1 \times 10^{14} \\ 8.6 \times 10^{13} \end{array}$	1.3×10^{14} 7.7×10^{13} 5.4×10^{13}	4.1 × 10 ¹³
	Front cover	75	2.2×10^{14} 1.3×10^{14} 1.0×10^{14}	$\begin{array}{rrrr} 1.9 \times 10^{14} \\ 1.2 \times 10^{14} \\ 1.0 \times 10^{14} \\ 1.0 \times 10^{14} \end{array}$	$\begin{array}{cccc} 1.7 & \times & 10^{14} \\ 1.1 & \times & 10^{14} \\ 8.8 & \times & 10^{13} \end{array}$	5.5×10^{13}
		50	2.3×10^{14} 1.4×10^{14} 1.1×10^{14} 1.1×10^{14}	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\begin{array}{rrrr} 1.8 \times 10^{14} \\ 1.2 \times 10^{14} \\ 1.0 \times 10^{14} \end{array}$	6.8 × 10 ¹³
		25	$\begin{array}{rrrr} 2.9 \times 10^{14} \\ 2.0 \times 10^{14} \\ 1.8 \times 10^{14} \end{array}$	$\begin{array}{cccc} 2.7 \times 10^{14} \\ 2.0 \times 10^{14} \\ 1.7 \times 10^{14} \end{array}$	$\begin{array}{rrrr} 2.4 \times 10^{14} \\ 1.8 \times 10^{14} \\ 1.6 \times 10^{14} \end{array}$	1.3 × 10 ¹⁴
	Rear shielding	(mg cm ⁻²)	12 17 34	12 17 34	12 17 34	Infinite
	Cell thickness	(шл)	125	200	300	125 200 300

EQUIVALENT IMEV ELECTRON FLUENCE FROM SOLAR FLARE PROTONS AND TRAPPED ELECTRONS,

FRONT AND REAR INCIDENCE, FOR PERIOD 1975-80

	300	$\begin{array}{c} 2.3 \times 10^{15} \\ 1.3 \times 10^{15} \\ 1.0 \times 10^{15} \end{array}$	$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\frac{1.8 \times 10^{15}}{1.2 \times 10^{15}}$ $\frac{0.9 \times 10^{15}}{0.9 \times 10^{15}}$).3 × 10 ¹⁵
(mu)	150	$\begin{array}{c} 2.5 \times 10^{15} \\ 1.5 \times 10^{15} \\ 1.2 \times 10^{15} \\ 1.2 \times 10^{15} \end{array}$	$\begin{array}{c} 2.2 \times 10^{15} \\ 1.5 \times 10^{15} \\ 1.3 \times 10^{15} \\ 1.3 \times 10^{15} \end{array}$	$\begin{array}{c} 1.9 \times 10^{15} \\ 1.4 \times 10^{15} \\ 1.1 \times 10^{15} \\ 1.1 \times 10^{15} \end{array}$	0.5 × 10 ¹⁵
r thickness (100	$\begin{array}{c} 2.7 \times 10^{15} \\ 1.7 \times 10^{15} \\ 1.5 \times 10^{15} \end{array}$	$\begin{array}{c} 2.4 \times 10^{15} \\ 1.7 \times 10^{15} \\ 1.4 \times 10^{15} \end{array}$	$\begin{array}{c} 2.1 \times 10^{15} \\ 1.6 \times 10^{15} \\ 1.3 \times 10^{15} \end{array}$	0.7 × 10 ¹⁵ (
Front cover	75	$\begin{array}{rrrr} 2.9 \times 10^{15} \\ 2.0 \times 10^{15} \\ 1.6 \times 10^{15} \end{array}$	$\begin{array}{c} 2.6 \times 10^{15} \\ 1.9 \times 10^{15} \\ 1.6 \times 10^{15} \\ 1.6 \times 10^{15} \end{array}$	$\begin{array}{c} 2.4 \times 10^{15} \\ 1.8 \times 10^{15} \\ 1.5 \times 10^{15} \end{array}$	0.9 × 10 ¹⁵
	50	$\begin{array}{c} 3.0 \times 10^{15} \\ 2.1 \times 10^{15} \\ 1.7 \times 10^{15} \end{array}$	$\begin{array}{c} 2.8 \times 10^{15} \\ 2.0 \times 10^{15} \\ 1.7 \times 10^{15} \end{array}$	$\begin{array}{c} 2.5 \times 10^{15} \\ 1.9 \times 10^{15} \\ 1.6 \times 10^{15} \\ 1.6 \times 10^{15} \end{array}$	1.0 × 10 ¹⁵
	25	$\begin{array}{c} 3.6 \times 10^{15} \\ 2.7 \times 10^{15} \\ 2.4 \times 10^{15} \end{array}$	$\begin{array}{r} 3.4 \times 10^{15} \\ 2.7 \times 10^{15} \\ 2.3 \times 10^{15} \end{array}$	$\begin{array}{r} 3.1 \times 10^{15} \\ 2.5 \times 10^{15} \\ 2.2 \times 10^{15} \\ 2.2 \times 10^{15} \end{array}$	1.7 × 10 ¹⁵
Rear shielding	(mg cm ⁻²)	12 17 34	12 17 34	12 17 34	Infinite
Cell thickness	(шл)	125	200	300	125 200 300

105

16

Table 6

SUMMARY OF ESTIMATES, 125µm CELL

	300	1.3×10^{15}	40.7	0.437	1.0 × 10 ¹⁵	0.3×10^{15}	41.8	45.0	0.877
(II	150	1.5 × 10 ¹⁵	40.1	0.298	1.2 × 10 ¹⁵	0.5 × 10 ¹⁵	41.0	43.9	0.738
ont cover (µ	100	1.7 × 10 ¹⁵	39.5	0.251	1.5 × 10 ¹⁵	0.7 × 10 ¹⁵	40.1	43.0	0.691
FT	75	1.9 × 10 ¹⁵	0. 9	0.228	1.6 × 10 ¹⁵	0.9 × 10 ¹⁵	39.9	42.1	0.668
	50	2.0 × 10 ¹⁵	38.8	0.205	1.7 × 10 ¹⁵	1.0×10^{15}	39.5	41.8	0.645
	25	2.7 × 10 ¹⁵	37.3	0.182	2.4×10^{15}	1.7 × 10 ¹⁵	37.8	39.5	0.622
ter		V electron 0 (cm ⁻²)	ximum (mW)	of solar	100μm Al. rear shielding	Infinite rear shielding	100µm Al. rear shielding	Infinite rear shielding	f solar
Parame		Equivalent lMe fluence 1975-8	End of life ma power at 620C	Specific mass panel (g/cell)	Equivalent IMeV electron	fluence 1975-80 (cm ⁻²)	End of life maximum nower	at 62oC (mW)	Specific mass c panel (g/cell)
Array	гуре		Flexible				Rigid		

SUMMARY OF ESTIMATES, 200µm CELL

Array	Ратапе	a tor	 		Froi	nt cover (µm)		
type			25	50	75	100	150	300
	Equivalent 1MeV fluence 1975-80	/ electron) (cm ⁻²)	2.7 × 10 ¹⁵	2.0×10^{15}	1.9 × 10 ¹⁵	1.7 × 10 ¹⁵	1.5×10^{15}	1.3 × 10 ¹⁵
Flexibie	End of life max power at 62°C (rimum (mW)	37.3	38.8	39.0	39.5	40.1	40.7
	Specific mass o panel (g/cell)	f solar	0.253	0.276	0.300	0.323	0.369	0.508
	Equivalent IMeV electron	100µm Al. rear shielding	2.3 × 10 ¹⁵	1.7 × 10 ¹⁵	1.6 × 10 ¹⁵	1.4 × 10 ¹⁵	1.3 × 10 ¹⁵	1.1 × 10 ¹⁵
	fluence, 1975-80 (cm ⁻²)	Infinite rear shielding	1.7 × 10 ¹⁵	1.0 × 10 ¹⁵	0.9 × 10 ¹⁵	0.7×10^{15}	0.5 × 10 ¹⁵	0.3×10^{15}
Rigid	End of life maximum power	100μm Al. rear shielding	38.1	39.5	39.9	40.2	40.7	41.4
	at 62°C (mW)	Infinite rear shielding	39.5	41.8	42.1	43.0	43.9	45.0
	Specific mass of panel (g/cell)	f solar	0.693	0.716	0.740	0.763	0.809	0.948

105

SUMMARY OF ESTIMATES, 300µm CELL

Array	Daram				Fron	t cover (µm)		
type		101	25	50	75	100	150	300
	Equivalent Me/ fluence, 1975-6	/ electron 30 (cm ⁻ 2)	2.5 × 10 ¹⁵	1.9 × 10 ¹⁵	1.8 × 10 ¹⁵	1.6 × 10 ¹⁵	1.4 × 10 ¹⁵	1.2×10^{15}
Flexible	End of life may power at 62°C (cimum (mW)	37.7	39.0	39.3	6.95	40.2	41.0
	Specific mass c panel (g/cell)	£ solar	0.347	0.370	0.394	0.417	0.463	0.602
	Equivalent 1 MeV electron	l00µm Al. rear shielding	2.2 × 10 ¹⁵	1.6 × 10 ¹⁵	1.5 × 10 ¹⁵	1.3 × 10 ¹⁵	1.1 × 10 ¹⁵	0.9 × 10 ¹⁵
	fluence, 1975-80 (cm ⁻²)	Infinite rear shielding	1.7 × 10 ¹⁵	1.0 × 10 ¹⁵	0.9 × 10 ¹⁵	0.7 × 10 ¹⁵	0.5 × 10 ¹⁵	0.3 × 10 ¹⁵
Rigid	End of life maximum power	l00µm Al. rear shielding	38.4	39.9	40.1	40.7	41.4	42.1
)	at 62°C (mW)	Infinite rear shielding	39.5	41.8	42.1	43.0	43.9	45.0
	Specific mass of panel (g/c∈ll)	E solar	0.787	0.810	0.834	0.857	0.903	1.042

18

REFERENCES

No.	Author	<u>Title, etc.</u>
1	-	Canadian Department of Communications Requirement - Spacecraft Environmental Design and Test Document. Ref. No. EV01-01 (1972)
2	-	NASA TMX 53865, 2nd edition, August, 1970
3	G. Brackley K. Lawson D.W. Satchell	Integral covers for silicon solar cells. 9th IEEE Photoveltaic Specialists Conference. Silver Spring, Md., USA, May 1972
4	F.C. Treble	Status report on RAE advanced lightweight solar array development. RAE Technical Report 72109 (1972)
5	F.C. Treble M.W. Walkden A.F. Dunnet C. Whitehead (AWEE)	Proton damage in silicon solar cells - final report prepared for Communications Satellite Corporation. Washington, DC, USA, Contract CSC-SS-183, July 1971
6	R.L. Crabb M.W. Walkden	Energy dependence of electron damage in silicon solar cells. RAE Technical Report 68139 (1968)
7	F.C. Treble	Solar arrays for the next generation of communication satellites. RAE Technical Memorandum Space 185 (1972)
8	A.A. Dollery A.F. Dunnet N.S. Reed	Qualification of 280W lightweight solar array. RAE Technical Report (to be published)

104 T 10³ 11 Proton Flux > E cm⁻² sec⁻¹ 10² 10 100 101 102 103 Proton energy E (Mev)

> Fig. 1 Integrated low energy proton flux (>E) 1975-77

TR .73105







T.R 73105

Fig.3 Front incidence proton damage factors for uncovered cells



T.R.73105

Fig.4



Fig. 4 Mass-range of protons in SiO_2

T.A.73105

Fig.5



Fig.5 Exit versus incident energy for protons in Si O_2 covers

TR 73105



 $E_R = Energy$ of proton incident on rear shield $R_1 = Range$ in silicon after attenuation of rear shield t = Cell thickness $R_2 = Distance$ from front surface $E_F = Equivalent$ front incidence energy

K = Damage factor for EF



2

R2= L-RI



5

 $\kappa_{R} \equiv \kappa_{F}$

Fig.7 Determination of rear incidence damage factors

T.R.73103





passing through rear shields



T.R.73105

.



TR 73105







TR 73105



T.R 73105

•







Electron energy (Mev)

Fig.13 Mass range of electrons in SiO2

TA. 73105

T.R. 73105



Fig.15 Effect of front cover thickness on electron damage factors

Fig. 16



Fig.16 Exit versus incident energy for rear electrons in 3 rear shields

Fig. 17



Fig.17 Effect of rear shielding on electron damage factors

T.R. 73105



Fig.18 Effect of proton angle of incidence



MS23 and MS36 cells

T.R. 731 05

Fig.20



T.R.73105

Fig.21



Fig.21 Power to weight ratios

. T.R.73105